

***±15kV ESD-Protected, Slew-Rate-Limited, Fail-Safe,  
True RS-485 Transceivers***

**UM3352E SOP8/DIP8**

**General Description**

The UM3352E series are ±15kV ESD-protected, high-speed, half-duplex transceivers for RS-485 communication that contain one driver and one receiver. The device features fail-safe circuitry, which guarantees a logic-high receiver output when the receiver inputs are open, shorted or idle. This means that the receiver output will be logic high if all transmitters on a terminated bus are disabled (high impedance). The UM3352E features reduced slew-rate driver that minimizes EMI and reduces reflections caused by improperly terminated cables, allowing error-free data transmission up to 500kbps. It also features enhanced ESD protection. All transmitter outputs and receiver inputs incorporate advanced structures allowing them to survive ESD events in excess of ±8kV Human Body Mode and ±15kV IEC61000-4-2 Air Discharge Mode, ±8kV IEC61000-4-2 Contact Discharge Mode. New ESD structures protect the device whether or not it is powered up and without degrading the RS-485 common mode range of -7V to 12V. The UM3352E includes a hot swap circuit inside, which allows live cable insertion and removal. Proprietary protection circuit built on A and B ports, can dissipate high surge current up to 6A to ground.

The transceivers typically draw 450μA of supply current when unloaded, or when fully loaded with the drivers disabled. The device has a 1/8-unit-load receiver input impedance that allows up to 256 transceivers on the bus and are intended for half-duplex communications.

**Applications**

- RS-485 Transceivers
- Intelligent Meters and Sensors
- Industrial Control
- Lighting Systems
- Security Systems
- HVAC Application

**Features**

- ESD Protection for RS-485 I/O Pins
  - ±8kV—Human Body Mode
  - ±15kV—IEC61000-4-2, Air Discharge Mode
  - ±8kV—IEC61000-4-2, Contact Discharge Mode
- True Fail-Safe Receiver
- Enhanced Slew-Rate Limiting Facilitates Error-Free Data Transmission
- 2μA Low-Current Shutdown Mode
- -7V to +12V Common-Mode Input Voltage Range
- Allows up to 256 Transceivers on the Bus
- Thermal Shutdown
- Current-Limiting for Driver Overload Protection
- Hot Swap Capability

**Ordering Information**

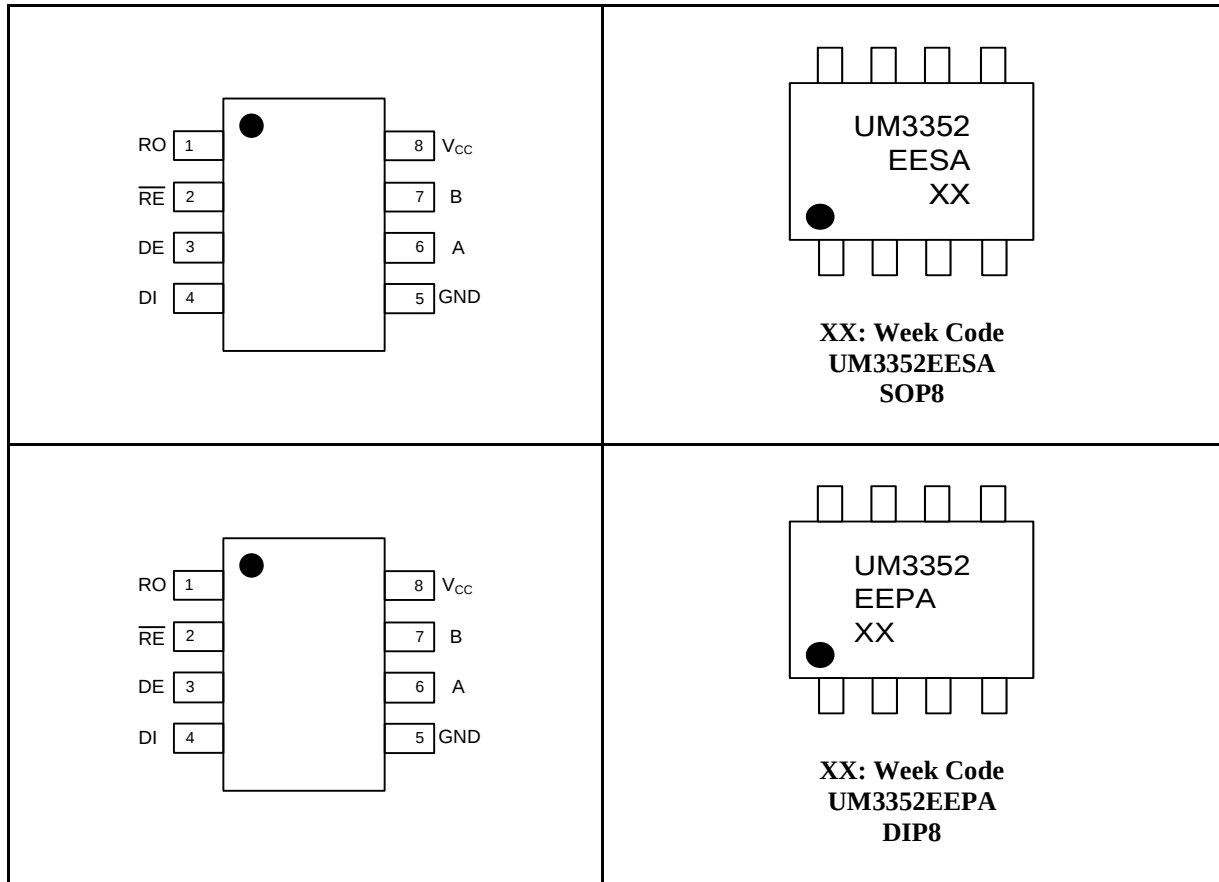
| Part Number | Operating Temperature | Mark Code  | Package Type | Shipping Qty                |
|-------------|-----------------------|------------|--------------|-----------------------------|
| UM3352EESA  | -40 °C to +85 °C      | UM3352EESA | SOP8         | 3000pcs/13 Inch Tape & Reel |
| UM3352EEPA  | -40 °C to +85 °C      | UM3352EEPA | DIP8         | 50pcs/Tube                  |

**Device Electrical Characteristic Summary**

| Part Number | Guaranteed Data Rate (Mbps) | Low-Power Shutdown | Slew-Rate Limited | Driver/Receiver Enable | Shutdown Current (μA) | Transceivers On Bus | ±15kV ESD Protection |
|-------------|-----------------------------|--------------------|-------------------|------------------------|-----------------------|---------------------|----------------------|
| UM3352E     | 0.5                         | Yes                | Yes               | Yes                    | 2                     | 256                 | Yes                  |

## Pin Configurations

## Top View



## Pin Description

| Pin Number | Symbol                 | Function                                                                                                                                                  |
|------------|------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1          | RO                     | Receiver Output. If $A > B$ by $-50\text{mV}$ , RO will be high; if $A < B$ by $200\text{mV}$ , RO will be low.                                           |
| 2          | $\overline{\text{RE}}$ | Receiver Output Enable. Drive RE low to enable Receiver, RO is high impedance when RE is high. Drive RE high and DE low to enter low-power shutdown mode. |
| 3          | DE                     | Driver Enable. Drive DE high to enable drivers. The outputs are high impedance when DE is low. Drive RE high and DE low to enter low-power shutdown mode. |
| 4          | DI                     | Driver Input. A low on DI forces output A low and output B high. Similarly, a high on DI forces output A high and output B low.                           |
| 5          | GND                    | Ground.                                                                                                                                                   |
| 6          | A                      | Non-Inverting Receiver Input and Non-Inverting Driver Output.                                                                                             |
| 7          | B                      | Inverting Receiver Input and Inverting Driver Output.                                                                                                     |
| 8          | V <sub>CC</sub>        | Power Supply for RS-485 Transceiver.                                                                                                                      |

**Absolute Maximum Ratings**

| Symbol    | Parameter                                     | Value                        | Unit |
|-----------|-----------------------------------------------|------------------------------|------|
| $V_{CC}$  | Supply Voltage                                | +7                           | V    |
|           | Control Input Voltage ( $\overline{RE}$ , DE) | -0.3V to ( $V_{CC} + 0.3V$ ) | V    |
|           | Driver Input Voltage (DI)                     | -0.3V to ( $V_{CC} + 0.3V$ ) | V    |
|           | Driver Output Voltage (A, B)                  | -7.5 to +12.5                | V    |
|           | Receiver Input Voltage (A, B)                 | -7.5 to +12.5                | V    |
|           | Receiver Output Voltage (RO)                  | -0.3V to ( $V_{CC} + 0.3V$ ) | V    |
| $T_A$     | Ambient Temperature                           | -40 to +85                   | °C   |
| $T_{STG}$ | Storage Temperature Range                     | -65 to +160                  | °C   |
| $T_L$     | Lead Temperature for Soldering 10 seconds     | +300                         | °C   |

**DC Electrical Characteristics**

( $V_{CC}=+5V \pm 5\%$ ,  $T_A=-40\text{ °C}$  to  $+85\text{ °C}$ , unless otherwise noted. Typical values are at  $V_{CC}=+5V$  and  $T_A=+25\text{ °C}$ .) (Note 1)

| Parameter                                          | Symbol          | Test Conditions                               | Min                                                       | Typ  | Max  | Unit |
|----------------------------------------------------|-----------------|-----------------------------------------------|-----------------------------------------------------------|------|------|------|
| <b>SUPPLY CURRENT</b>                              |                 |                                               |                                                           |      |      |      |
| Supply Current                                     | $I_{CC}$        | No Load,<br>DI=GND<br>or $V_{CC}$             | $\overline{DE}=V_{CC},$<br>$\overline{RE}=0V$ or $V_{CC}$ |      | 0.45 | mA   |
|                                                    |                 |                                               | $\overline{DE}=0V,$<br>$\overline{RE}=0V$                 |      | 0.45 |      |
| Supply Current in Shutdown Mode                    | $I_{SHDN}$      | $\overline{DE} = GND, \overline{RE} = V_{CC}$ |                                                           | 2    |      | µA   |
| <b>LOGIC</b>                                       |                 |                                               |                                                           |      |      |      |
| Input High Voltage                                 | $V_{IH}$        | DE, DI, $\overline{RE}$                       | 2.0                                                       |      |      | V    |
| Input Low Voltage                                  | $V_{IL}$        | DE, DI, $\overline{RE}$                       |                                                           |      | 0.8  | V    |
| Input Hysteresis                                   | $V_{HYS}$       | DE, DI, $\overline{RE}$                       |                                                           | 100  |      | mV   |
| Input Leakage Current                              | $I_{LEAK}$      | DE, DI, $\overline{RE}$                       |                                                           |      | ±2   | µA   |
| <b>DRIVER</b>                                      |                 |                                               |                                                           |      |      |      |
| Differential Driver Output                         | $V_{OD1}$       | No Load, Figure 2                             |                                                           |      | 5    | V    |
| Differential Driver Output                         | $V_{OD2}$       | Figure 2, $R_{LOAD}=50\Omega$                 | 1.5                                                       |      |      | V    |
| Change-in-Magnitude of Differential Output Voltage | $\Delta V_{OD}$ | Figure 2, $R_{LOAD}=50\Omega$<br>(Note 2)     |                                                           |      | 0.2  | V    |
| Driver Common-Mode Output Voltage                  | $V_{OC}$        | Figure 2, $R_{LOAD}=50\Omega$                 |                                                           |      | 3.0  | V    |
| Change-in-Magnitude of Common-Mode Voltage         | $\Delta V_{OC}$ | Figure 2, $R_{LOAD}=50\Omega$<br>(Note 2)     |                                                           |      | 0.2  | V    |
| Driver Short-Circuit Output Current (Note 3)       | $I_{OSD}$       | $V_{OUT}=-7V$                                 |                                                           | -250 |      | mA   |
|                                                    |                 | $V_{OUT}=12V$                                 |                                                           | 250  |      |      |

**DC Electrical Characteristics (Continued)**

( $V_{CC}=+5V \pm 5\%$ ,  $T_A=-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$ , unless otherwise noted. Typical values are at  $V_{CC}=+5V$  and  $T_A=+25\text{ }^{\circ}\text{C}$ .) (Note 1)

| Parameter                               | Symbol           | Test Conditions                                         |                      | Min                  | Typ | Max  | Unit |
|-----------------------------------------|------------------|---------------------------------------------------------|----------------------|----------------------|-----|------|------|
| RECEIVER                                |                  |                                                         |                      |                      |     |      |      |
| Receiver Differential Threshold Voltage | V <sub>TH</sub>  | -7V≤V <sub>CM</sub> ≤12V                                |                      | -200                 |     | -50  | mV   |
| Receiver Input Hysteresis               | ΔV <sub>TH</sub> | V <sub>CM</sub> =0V                                     |                      |                      | 25  |      | mV   |
| Receiver Input Resistance               | R <sub>IN</sub>  | -7V≤V <sub>CM</sub> ≤12V                                |                      | 96                   |     |      | kΩ   |
| Input Current (A and B)                 | I <sub>IN2</sub> | DE=GND, V <sub>CC</sub> =GND or 5V                      | V <sub>IN</sub> =12V |                      |     | 1.0  | mA   |
|                                         |                  |                                                         | V <sub>IN</sub> =-7V |                      |     | -0.8 |      |
| Receiver Output High Voltage            | V <sub>OH</sub>  | I <sub>O</sub> =-1.5mA, V <sub>ID</sub> =+200mV         |                      | V <sub>CC</sub> -1.5 |     |      | V    |
| Receiver Output Low Voltage             | V <sub>OL</sub>  | I <sub>O</sub> =2.5mA, V <sub>ID</sub> =-200mV          |                      |                      |     | 0.4  | V    |
| Three-State Output Current at Receiver  | I <sub>OZR</sub> | V <sub>CC</sub> =5V, 0V≤V <sub>O</sub> ≤V <sub>CC</sub> |                      |                      |     | ±1   | μA   |
| Receiver Output Short Circuit Current   | I <sub>OSR</sub> | 0V≤V <sub>RO</sub> ≤V <sub>CC</sub>                     |                      | ±8                   |     | ±60  | mA   |
| ESD Protection                          |                  |                                                         |                      |                      |     |      |      |
| ESD Protection for A, B                 |                  | Human Body Mode                                         |                      |                      | ±8  |      | kV   |
|                                         |                  | IEC61000-4-2<br>Air Discharge Mode                      |                      |                      | ±15 |      |      |
|                                         |                  | IEC61000-4-2<br>Contact Discharge Mode                  |                      |                      | ±8  |      |      |

Note 1: All currents into the device are positive; all currents out of the device are negative. All voltages are referred to device ground unless otherwise noted.

Note 2:  $\Delta V_{OD}$  and  $\Delta V_{OC}$  are the changes in  $V_{OD}$  and  $V_{OC}$ , respectively, when the DI input changes state.

Note 3: Maximum current level applies to peak current just prior to fold back current limiting; minimum current level applies during current limiting.

**Switching Characteristics**

( $V_{CC}=+5V \pm 5\%$ ,  $T_A=-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$ , unless otherwise noted. Typical values are at  $V_{CC}=+5V$  and  $T_A=+25\text{ }^{\circ}\text{C}$ .)

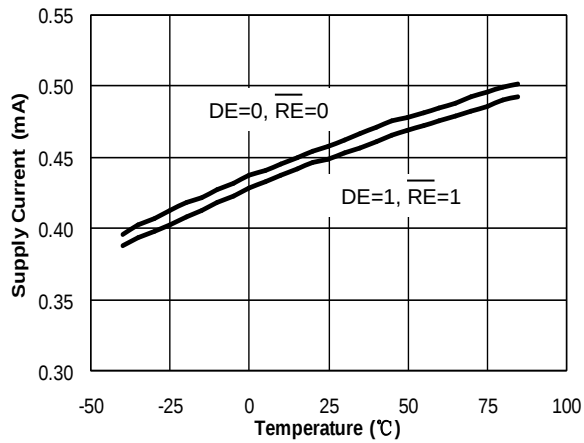
| Parameter                                             | Symbol               | Test Conditions                                                                            | Min | Typ | Max  | Unit |
|-------------------------------------------------------|----------------------|--------------------------------------------------------------------------------------------|-----|-----|------|------|
| Maximum Data Rate                                     | $f_{MAX}$            |                                                                                            |     | 500 |      | kbps |
| Driver Input-to-Output                                | $t_{DPLH}$           | Figures 3 and 7, $R_{DIFF}=54\Omega$ ,<br>$C_{L1}=C_{L2}=100\text{pF}$                     |     | 50  | 1000 | ns   |
|                                                       | $t_{DPHL}$           |                                                                                            |     | 50  | 1000 |      |
| Driver Output Skew<br>  $t_{DPLH} - t_{DPHL}$         | $t_{DSKEW}$          | Figures 3 and 7, $R_{DIFF}=54\Omega$ ,<br>$C_{L1}=C_{L2}=100\text{pF}$                     |     | 15  | 100  | ns   |
| Driver Rise or Fall Time                              | $t_{DR}, t_{DF}$     | Figures 3 and 7, $R_{DIFF}=54\Omega$ ,<br>$C_{L1}=C_{L2}=100\text{pF}$                     |     | 100 | 750  | ns   |
| Driver Enable to Output High                          | $t_{DZH}$            | Figures 4 and 8, $C_L=100\text{pF}$ ,<br>S2 Closed                                         |     | 30  | 2500 | ns   |
| Driver Enable to Output Low                           | $t_{DZL}$            | Figures 4 and 8, $C_L=100\text{pF}$ ,<br>S1 Closed                                         |     | 30  | 2500 | ns   |
| Driver Disable Time from Low                          | $t_{DLZ}$            | Figures 4 and 8, $C_L=15\text{pF}$ ,<br>S1 Closed                                          |     | 60  | 200  | ns   |
| Driver Disable Time from High                         | $t_{DHZ}$            | Figures 4 and 8, $C_L=15\text{pF}$ ,<br>S2 Closed                                          |     | 100 | 200  | ns   |
| Receiver Input to Output                              | $t_{RPLH}, t_{RPHL}$ | $ V_{ID}  \geq 2.0V$ ,<br>Rise and Fall Time of $V_{ID} \leq 15\text{ns}$                  |     | 75  | 200  | ns   |
| Differential Receiver Skew<br>  $t_{RPLH} - t_{RPHL}$ | $t_{RSKD}$           | Figures 6 and 9, $ V_{ID}  \geq 2.0V$ ,<br>Rise and Fall Time of $V_{ID} \leq 15\text{ns}$ |     | 0   | 30   | ns   |
| Receiver Enable to Output Low                         | $t_{RZL}$            | Figures 5 and 10, $C_L=100\text{pF}$ ,<br>S1 Closed                                        |     | 20  | 50   | ns   |
| Receiver Enable to Output High                        | $t_{RZH}$            | Figures 5 and 10, $C_L=100\text{pF}$ ,<br>S2 Closed                                        |     | 20  | 50   | ns   |
| Receiver Disable Time from Low                        | $t_{RLZ}$            | Figures 5 and 10, $C_L=100\text{pF}$ ,<br>S1 Closed                                        |     | 20  | 50   | ns   |
| Receiver Disable Time from High                       | $t_{RHZ}$            | Figures 5 and 10, $C_L=100\text{pF}$ ,<br>S2 Closed                                        |     | 20  | 50   | ns   |
| Time to Shutdown                                      | $t_{SHDN}$           | (Note 4)                                                                                   |     | 200 | 600  | ns   |
| Driver Enable from Shutdown to Output High            | $t_{DZH(SHDN)}$      | Figures 4 and 8, $C_L=15\text{pF}$ ,<br>S2 Closed                                          |     | 700 | 4500 | ns   |
| Driver Enable from Shutdown to Output Low             | $t_{DZL(SHDN)}$      | Figures 4 and 8, $C_L=15\text{pF}$ ,<br>S1 Closed                                          |     | 700 | 4500 | ns   |
| Receiver Enable from Shutdown to Output High          | $t_{RZH(SHDN)}$      | Figures 5 and 10, $C_L=100\text{pF}$ ,<br>S2 Closed                                        |     | 700 | 3500 | ns   |
| Receiver Enable from Shutdown to Output Low           | $t_{RZL(SHDN)}$      | Figures 5 and 10, $C_L=100\text{pF}$ ,<br>S1 Closed                                        |     | 700 | 3500 | ns   |

Note 4: The device is put into shutdown by bringing  $\overline{RE}$  high and DE low. If the enable inputs are in this state for less than 50ns, the device is guaranteed not to enter shutdown. If the enable inputs are in this state for at least 600ns, the device is guaranteed to have entered shutdown.

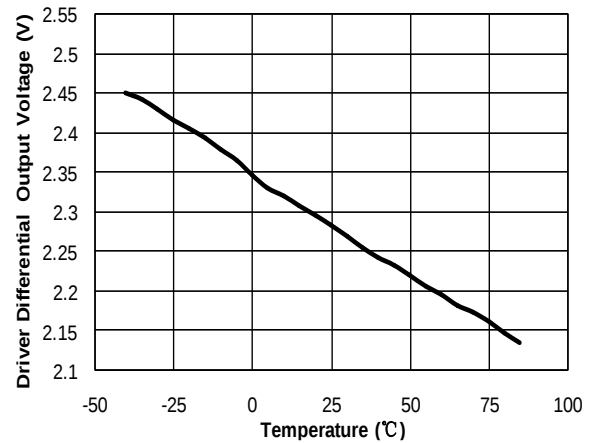
## Typical Operating Characteristics

( $V_{CC}=+5.0V$ ,  $T_A=+25^{\circ}C$ , unless otherwise noted.)

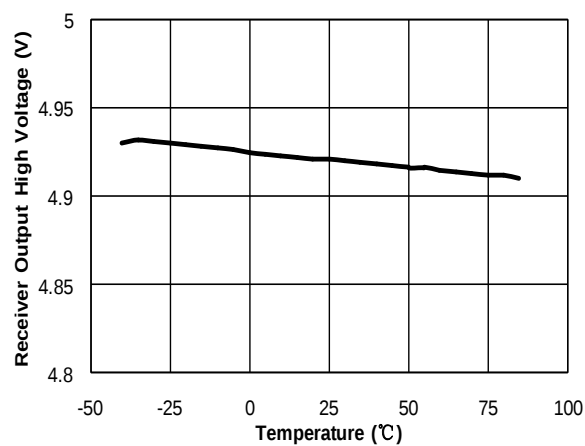
**Supply Current vs. Temperature**



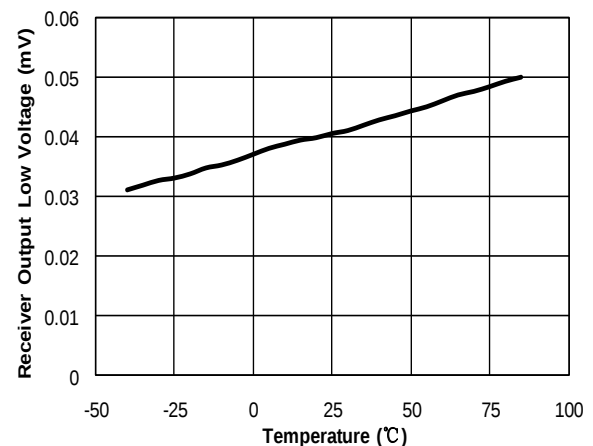
**Driver Differential Output Voltage vs. Temperature**  
 $R_{LOAD}=54\Omega$



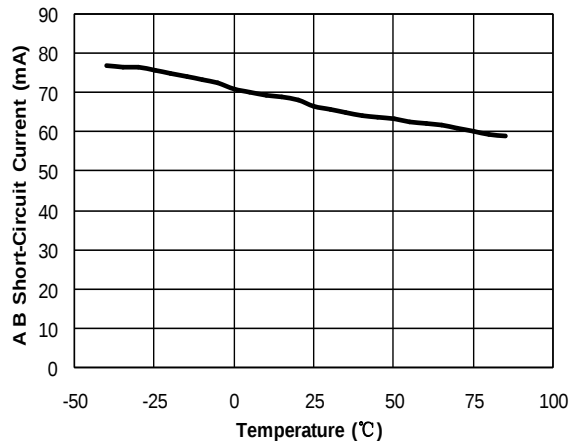
**Receiver Output High Voltage vs. Temperature**



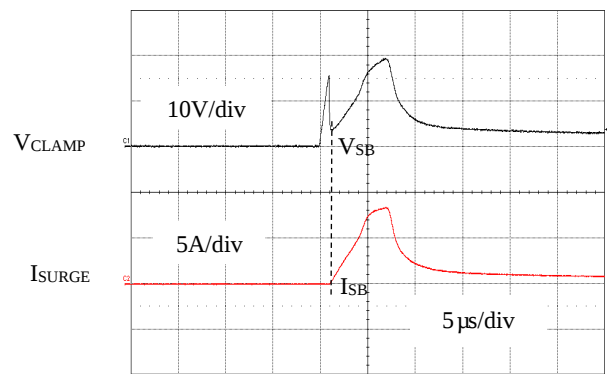
**Receiver Output Low Voltage vs. Temperature**



**A B Short-Circuit Current vs. Temperature**  
 $DI=1$

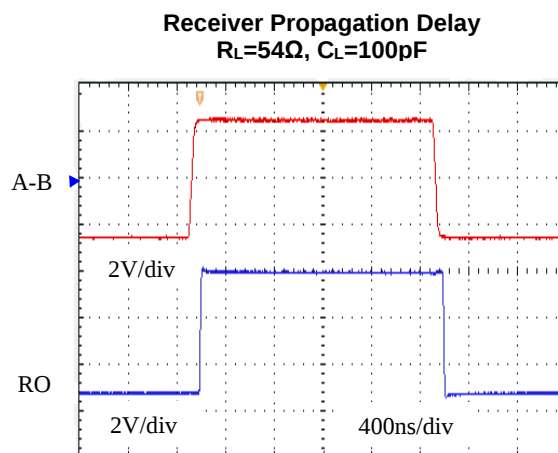
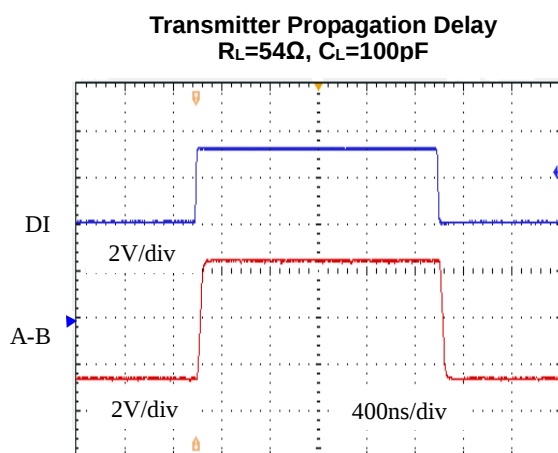


**A B Pin I-V Snap Back Characteristic**



**Typical Operating Characteristics (Continued)**

( $V_{CC}=+5.0V$ ,  $T_A=+25^{\circ}C$ , unless otherwise noted.)


**RS-485 Communication Function Table**
**Table1. Transmitting**

| INPUTS          |    |    | OUTPUTS  |        |
|-----------------|----|----|----------|--------|
| $\overline{RE}$ | DE | DI | B        | A      |
| X               | 1  | 1  | 0        | 1      |
| X               | 1  | 0  | 1        | 0      |
| 0               | 0  | X  | High-Z   | High-Z |
| 1               | 0  | X  | Shutdown |        |

X=Don't care; High-Z=High impedance

**Table2. Receiving**

| INPUTS |    |               | OUTPUTS  |
|--------|----|---------------|----------|
| RE     | DE | A-B           | RO       |
| 0      | X  | $\geq -50mV$  | 1        |
| 0      | X  | $\leq -200mV$ | 0        |
| 0      | X  | Open/Shorted  | 1        |
| 1      | 1  | X             | High-Z   |
| 1      | 0  | X             | Shutdown |

X=Don't care; High-Z=High impedance

## Typical Operating Circuit

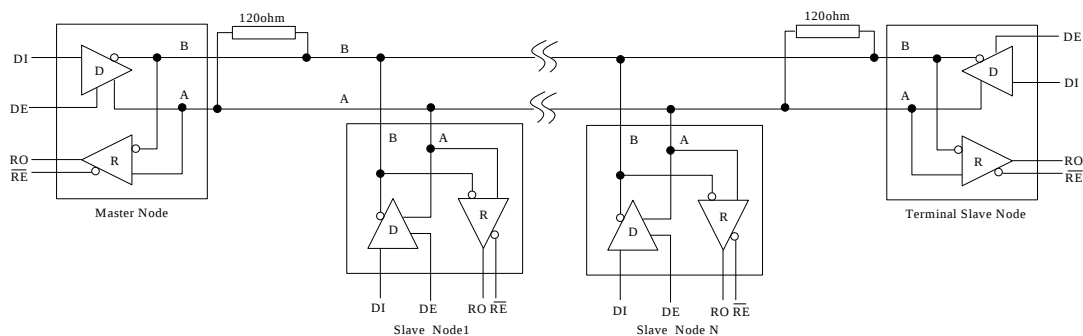


Figure 1. Typical Half-Duplex RS-485 Network

## Test Circuit

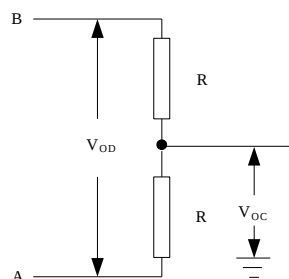


Figure 2. Driver DC Test Load

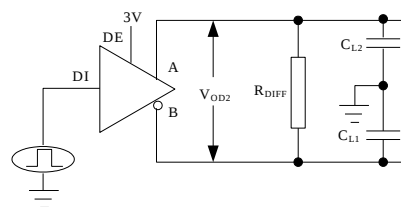


Figure 3. Driver Timing Test Circuit

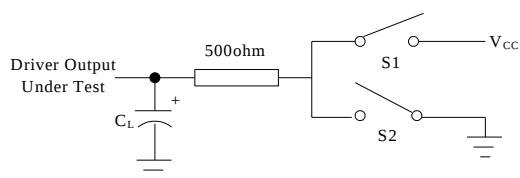


Figure 4. Driver Enable/Disable Timing Test Load

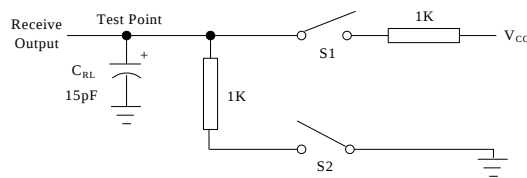


Figure 5. Receiver Enable/Disable Timing Test Load

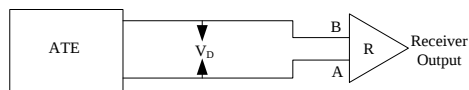


Figure 6. Receiver Propagation Delay Test Circuit

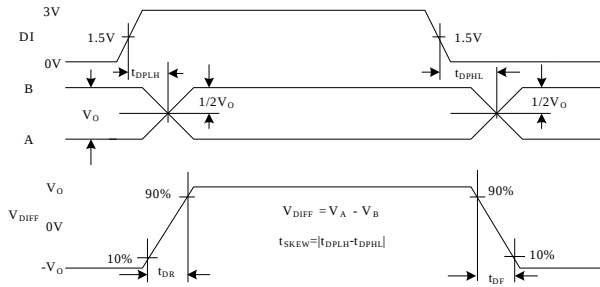


Figure 7. Driver Propagation Delays

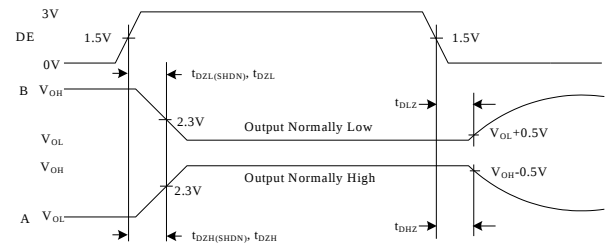


Figure 8. Driver Enable and Disable Times

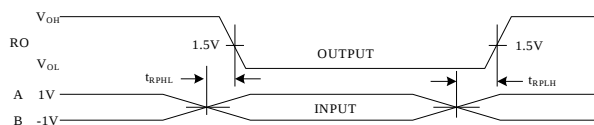


Figure 9. Receiver Propagation Delays

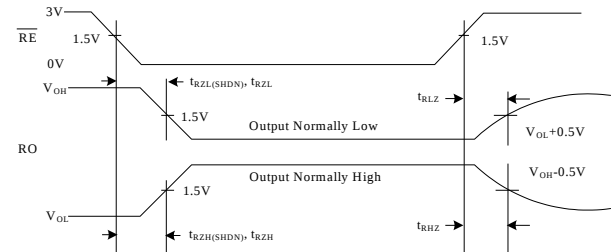


Figure 10. Receiver Enable and Disable Times

## Detail Description

The UM3352E high-speed transceivers for RS-485 communication contain one driver and one receiver. The device features fail-safe circuitry, which guarantees a logic-high receiver output when the receiver input is open or shorted, or when it is connected to a terminated transmission line with all drivers disabled. The UM3352E features reduced slew-rate driver that minimizes EMI and reduces reflections caused by improperly terminated cables, allowing error-free data transmission up to 500kbps. It operates from a single +5V supply. Drivers are output short-circuit current limited. Thermal shutdown circuitry protects drivers against excessive power dissipation. When activated, the thermal shutdown circuitry places the driver outputs into a high impedance state.

### Fail-Safe

The UM3352E guarantees a logic-high receiver output when the receiver inputs are shorted or open, or when they are connected to a terminated transmission line with all drivers disabled. This is done by setting the receiver threshold between -50mV and -200mV. If the differential receiver input voltage (A-B) is greater than or equal to -50mV, RO is logic high. If A-B is less than or equal to -200mV, RO is logic low. In the case of a terminated bus with all transmitters disabled, the receiver's differential input voltage is pulled to 0V by the termination. With the receiver thresholds of the UM3352E, this results in a logic high with a 50mV minimum noise margin. Unlike previous fail-safe devices, the -50mV to -200mV threshold complies with the  $\pm 200\text{mV}$  EIA/TIA-485 standard.

## Applications Information

### 256 Transceivers on the Bus

The standard RS-485 receiver input impedance is 12k $\Omega$  (one unit load), and the standard driver can drive up to 32 unit loads. The Union family of transceivers have a 1/8 unit load receiver input impedance (96k $\Omega$ ), allowing up to 256 transceivers to be connected in parallel on one communication line. Any combination of these devices, as well as other RS-485 transceivers with a total of 32 unit loads or fewer, can be connected to the line.

### Reduced EMI and Reflections

The UM3352E is slew-rate limited, minimizing EMI and reducing reflections caused by improperly terminated cables. In general, a transmitter's rise time relates directly to the length of an unterminated stub, which can be driven with only minor waveform reflections. The following equation expresses this relationship conservatively:

$$\text{Length} = t_{\text{RISE}} / (10 \times 1.5 \text{ ns/ft})$$

Where  $t_{\text{RISE}}$  is the transmitter's rise time.

A system can work well with longer unterminated stubs, even with severe reflections, if the waveform settles out before the receiver's UART samples them.

### Low-Power Shutdown Mode

Low-power shutdown mode is initiated by bringing both  $\overline{\text{RE}}$  high and DE low. In shutdown, the device typically draws only 2 $\mu\text{A}$  of supply current.  $\overline{\text{RE}}$  and DE may be driven simultaneously; the parts are guaranteed not to enter shutdown if  $\overline{\text{RE}}$  is high and DE is low for less than 50ns. If the inputs are in this state for at least 600ns, the parts are guaranteed to enter shutdown. Enable times  $t_{\text{ZH}}$  and  $t_{\text{ZL}}$  in the Switching Characteristics tables assume the part was not in a low-power shutdown state. Enable times  $t_{\text{ZH(SHDN)}}$  and  $t_{\text{ZL(SHDN)}}$  assume the parts were shut down. It takes drivers and receivers longer to become enabled from low-power shutdown mode ( $t_{\text{ZH(SHDN)}}$ ,  $t_{\text{ZL(SHDN)}}$ ) than from driver/receiver-disable mode ( $t_{\text{ZH}}$ ,  $t_{\text{ZL}}$ ).

### Driver Output Protection

Two mechanisms prevent excessive output current and power dissipation caused by faults or by bus contention. The first, a foldback current limit on the output stage, provides immediate protection against short circuits over the whole common-mode voltage range. The second, a thermal shutdown circuit, forces the driver outputs into a high-impedance state if the die temperature becomes excessive.

### Line Length vs. Data Rate

The RS-485/RS-422 standard covers line lengths up to 4000 feet. For line lengths greater than 4000 feet, repeater is required.

### ESD Protection

All pins on these devices include class 2 (>2kV) Human Body Model (HBM) ESD protection structures, but the RS-485 pins (driver outputs and receiver inputs) incorporate advanced structures allowing them to survive ESD events in excess of  $\pm 8\text{kV}$  HBM,  $\pm 15\text{kV}$  IEC61000-4-2 Air Discharge Mode and  $\pm 8\text{kV}$  IEC61000-4-2 Contact Discharge Mode. The RS-485 pins are particularly vulnerable to ESD strikes because they typically connect to an exposed port on the exterior of the finished product. Simply touching the port pins, or connecting a cable, can cause an ESD event that might destroy unprotected ICs.

These new ESD structures protect the device whether or not it is powered up, and without degrading the RS-485 common mode range of -7V to +12V. This built-in ESD protection cuts the need for board level protection structures (e.g., transient suppression diodes), and the associated, undesirable capacitive load they present.

**IEC61000-4-2 Testing**

The IEC61000 test method applies to finished equipments, rather than to an individual IC. Therefore, the pins most likely to suffer an ESD event are those that are exposed to the outside world (the RS-485 pins in this case), and the IC is tested in its typical application configuration (power applied) rather than testing each pin-to-pin combination. The IEC61000 standard's lower current limiting resistor coupled with the larger charge storage capacitor yields a test that is much more severe than the HBM test.

**Air-Gap Discharge Test Method**

For this test method, a charged probe tip moves toward the IC pin until the voltage arcs to it. The current waveform delivered to the IC pin depends on approach speed, humidity, temperature, etc., so it is difficult to obtain repeatable results. The UM3352E RS-485 pins withstand  $\pm 15\text{kV}$  air-gap discharges.

**Contact Discharge Test Method**

During the contact discharge test, the probe contacts the tested pin before the probe tip is energized, thereby eliminating the variables associated with the air-gap discharge. The result is a more repeatable and predictable test, but equipment limits prevent testing devices at voltages higher than  $\pm 8\text{kV}$ . The RS-485 pins of all the UM3352E versions survive  $\pm 8\text{kV}$  contact discharges.

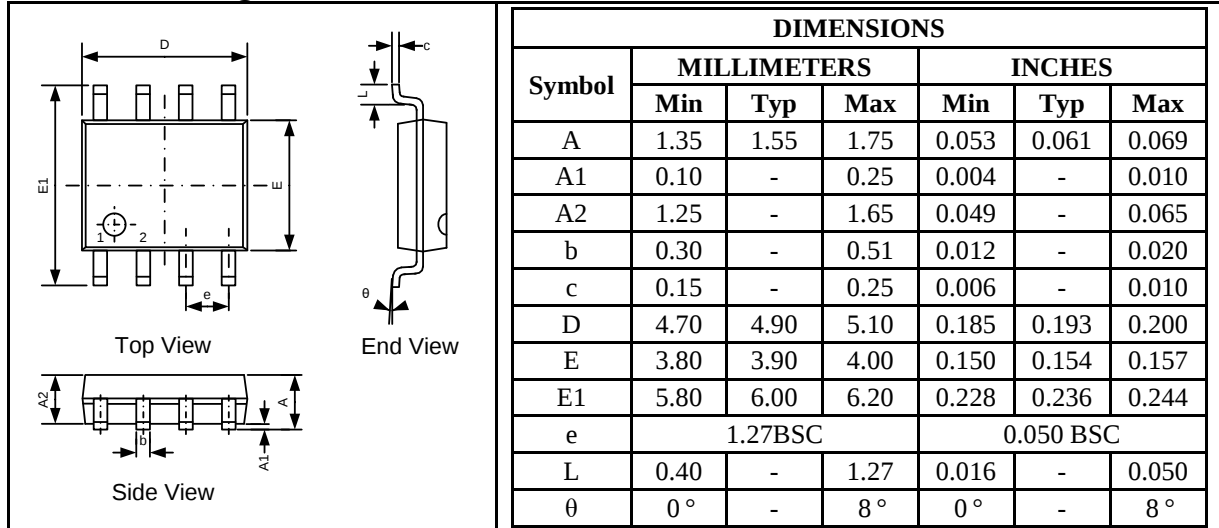
**Typical Applications**

The UM3352E transceivers are designed for bidirectional data communications on multipoint bus transmission lines. To minimize reflections, the line should be terminated at both ends in its characteristic impedance, and stub lengths of the main line should be kept as short as possible.

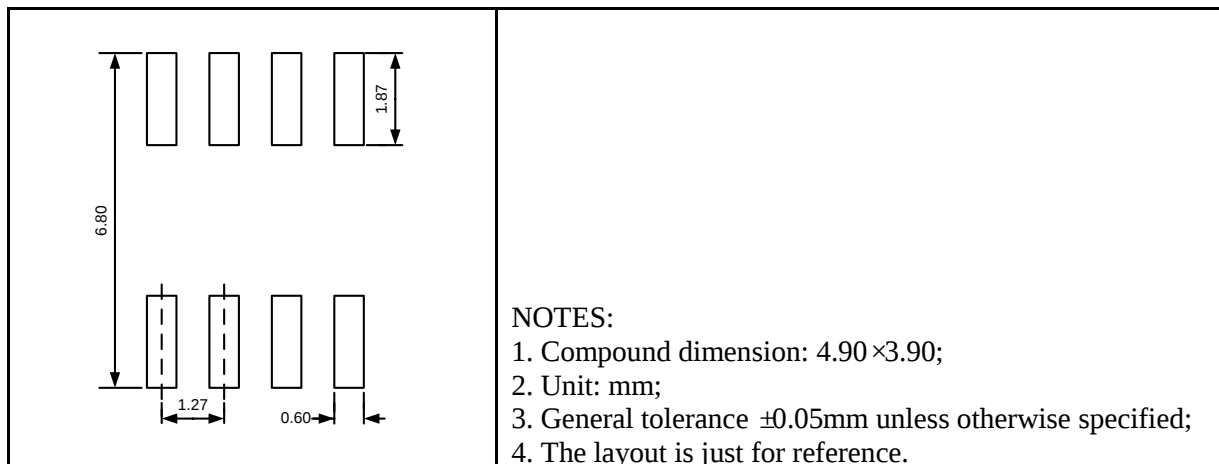
## Package Information

### UM3352EESA SOP8

#### Outline Drawing

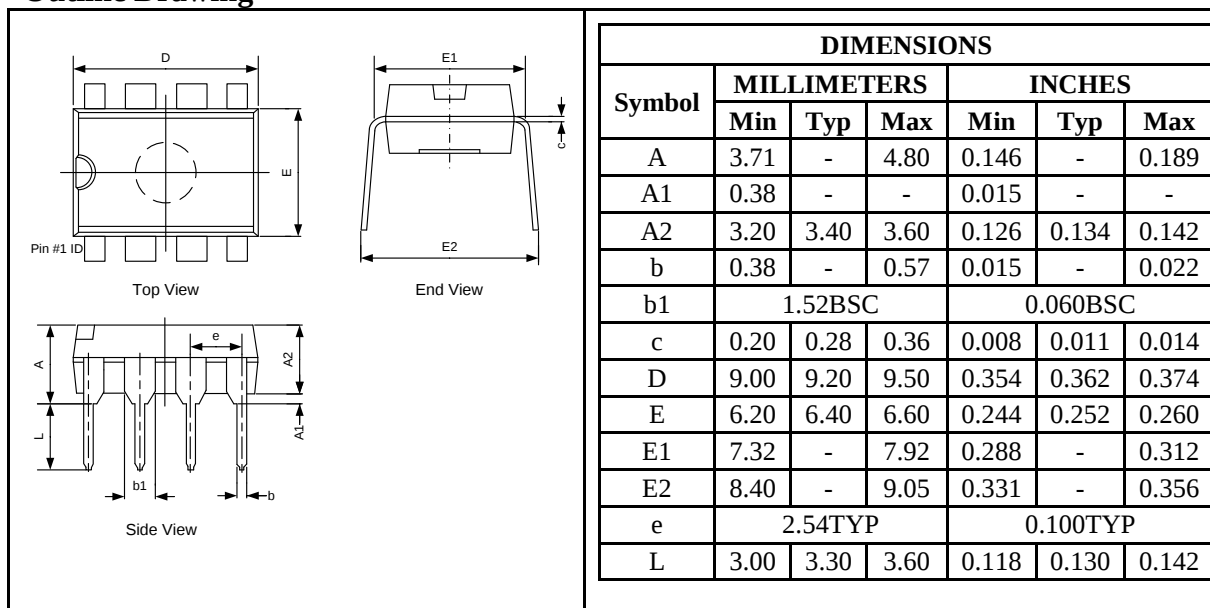


#### Land Pattern

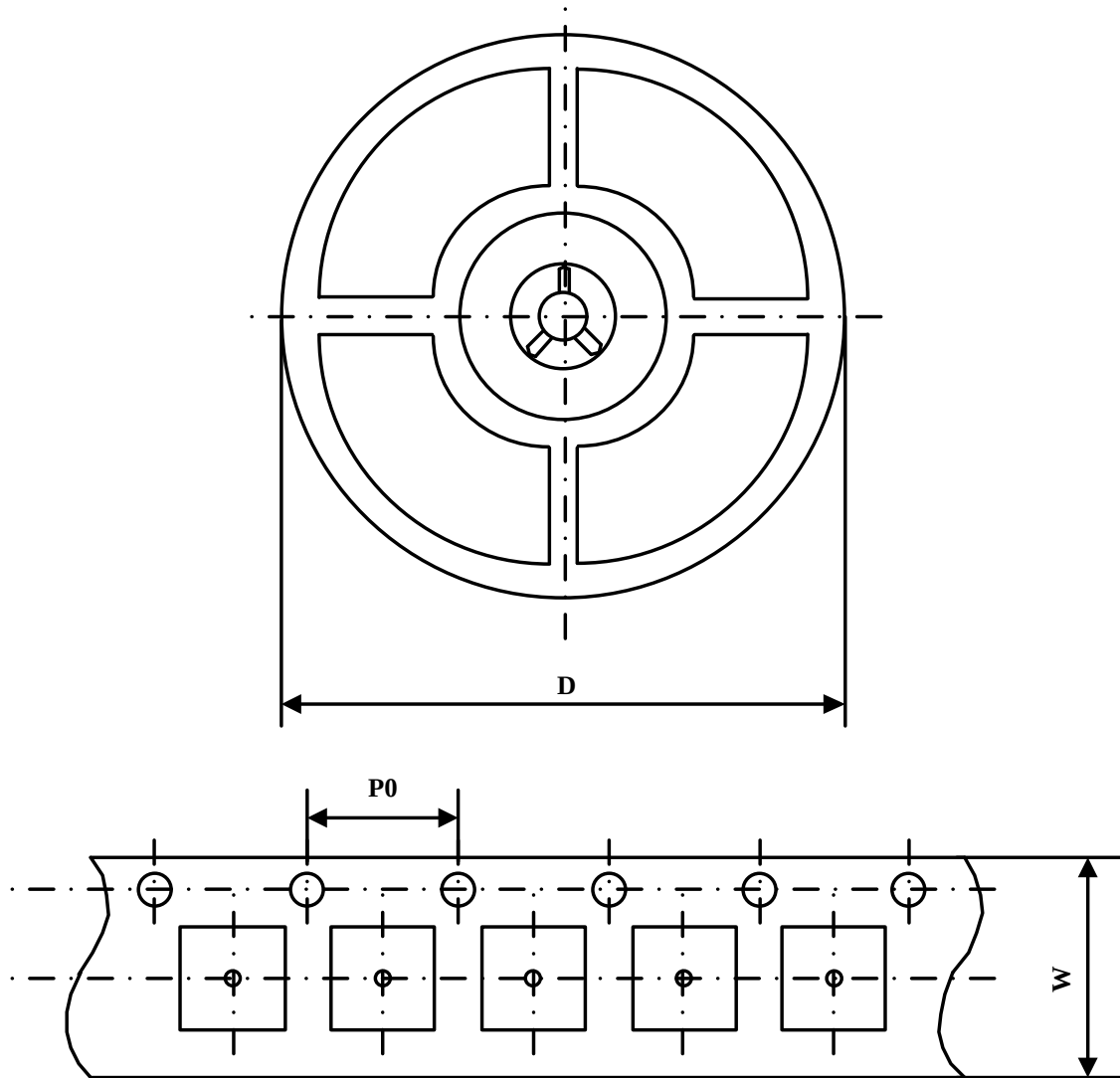


#### Tape and Reel Orientation



**UM3352EEPA DIP8**
**Outline Drawing**


## Packing Information



| Part Number | Package Type | Carrier Width(W) | Pitch(P0) | Reel Size(D) |
|-------------|--------------|------------------|-----------|--------------|
| UM3352EESA  | SOP8         | 12 mm            | 4 mm      | 330 mm       |

---

## **GREEN COMPLIANCE**

Union Semiconductor is committed to environmental excellence in all aspects of its operations including meeting or exceeding regulatory requirements with respect to the use of hazardous substances. Numerous successful programs have been implemented to reduce the use of hazardous substances and/or emissions.

All Union components are compliant with the RoHS directive, which helps to support customers in their compliance with environmental directives. For more green compliance information, please visit:

[http://www.union-ic.com/index.aspx?cat\\_code=RoHSDeclaration](http://www.union-ic.com/index.aspx?cat_code=RoHSDeclaration)

## **IMPORTANT NOTICE**

The information in this document has been carefully reviewed and is believed to be accurate. Nonetheless, this document is subject to change without notice. Union assumes no responsibility for any inaccuracies that may be contained in this document, and makes no commitment to update or to keep current the contained information, or to notify a person or organization of any update. Union reserves the right to make changes, at any time, in order to improve reliability, function or design and to attempt to supply the best product possible.